## NSN 5961-00-052-4915

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-052-4915 **Inclosure Material:** Metal **Overall Length:** Between 0.300 inches and 0.400 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.424 inches and 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.9 forward voltage, peak and 2.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 30.00 milliamperes forward current, total rms preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnpn **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud **Specification Data:** 81349-mil-s-19500/168 government specification Shelf Life: N/a **Unit Of Measure:** 

Fiig: A110a0

No

**Demilitarization:**